

Data Sheet January 2000 File Number 2932.3

## 30A, 1000V Ultrafast Dual Diode

The RURH30100CC is an ultrafast dual diode with soft recovery characteristics ( $t_{rr}$  < 110ns). It has low forward voltage drop and is of silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as a freewheeling/clamping diode and rectifier in a variety of switching power supplies and other power switching applications. Its low stored charge and ultrafast recovery with soft recovery characteristic minimizes ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistors.

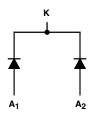
Formerly developmental type TA09904.

## **Ordering Information**

PART NUMBER	PACKAGE	BRAND
RURH30100CC	TO-218AC	URH30100C

NOTE: When ordering, use the entire part number.

# Symbol



### **Features**

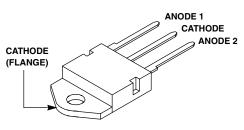
- · Avalanche Energy Rated
- Planar Construction

## **Applications**

- · Switching Power Supplies
- · Power Switching Circuits
- General Purpose

# **Packaging**

#### **JEDEC TO-218AC**



### **Absolute Maximum Ratings** (Per Leg) T<sub>C</sub> = 25°C, Unless Otherwise Specified

	RURH30100CC	UNITS
Peak Repetitive Reverse Voltage	1000	V
Working Peak Reverse Voltage	1000	V
DC Blocking Voltage	1000	V
Average Rectified Forward Current $I_{F(AV)}$ ( $T_C = 120^{\circ}C$ )	30	Α
Repetitive Peak Surge CurrentI <sub>FRM</sub> (Square Wave, 20kHz)	60	Α
Nonrepetitive Peak Surge Current	300	Α
Maximum Power Dissipation	125	W
Avalanche Energy (See Figures 7 and 8)	30	mJ
Operating and Storage Temperature	-65 to 175	οС

### RURH30100CC

**Electrical Specifications** (Per Leg) T<sub>C</sub> = 25°C, Unless Otherwise Specified

SYMBOL	TEST CONDITION	MIN	ТҮР	MAX	UNITS
V <sub>F</sub>	I <sub>F</sub> = 30A	-	-	1.8	V
	I <sub>F</sub> = 30A, T <sub>C</sub> = 150 <sup>o</sup> C	-	-	1.6	V
I <sub>R</sub>	V <sub>R</sub> = 1000V	-	-	250	μΑ
	$V_R = 1000V, T_C = 150^{\circ}C$	-	-	1	mA
t <sub>rr</sub>	I <sub>F</sub> = 1A, dI <sub>F</sub> /dt = 100A/μs	-	-	110	ns
	$I_F = 30A$ , $dI_F/dt = 100A/\mu s$	-	-	150	ns
t <sub>a</sub>	$I_F = 30A$ , $dI_F/dt = 100A/\mu s$	-	90	-	ns
t <sub>b</sub>	$I_F = 30A$ , $dI_F/dt = 100A/\mu s$	-	45	-	ns
$R_{ heta JC}$		-	-	1.2	°C/W

### **DEFINITIONS**

 $V_F$  = Instantaneous forward voltage (pw = 300 $\mu$ s, D = 2%).

I<sub>R</sub> = Instantaneous reverse current.

 $t_{rr}$  = Reverse recovery time (See Figure 6), at  $dI_F/dt = 100A/\mu s$  summation of  $t_a + t_b$ .

 $t_a$  = Time to reach peak reverse current at  $dI_F/dt$  = 100A/ $\mu$ s (See Figure 6).

t<sub>b</sub> = Time from peak I<sub>RM</sub> to projected zero crossing of I<sub>RM</sub> based on a straight line from peak I<sub>RM</sub> through 25% of I<sub>RM</sub> (See Figure 6).

 $R_{\theta JC}$  = Thermal resistance junction to case.

pw = Pulse width.

D = Duty cycle.

# **Typical Performance Curves**

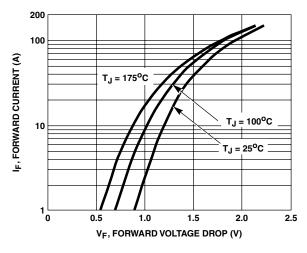


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

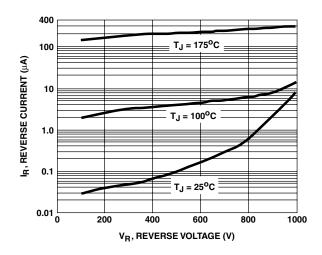


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

# Typical Performance Curves (Continued)

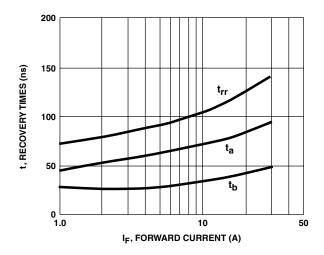


FIGURE 3.  $t_{rr}$ ,  $t_a$  AND  $t_b$  CURVES vs FORWARD CURRENT

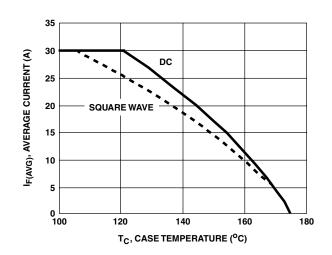


FIGURE 4. CURRENT DERATING CURVE

## Test Circuits and Waveforms

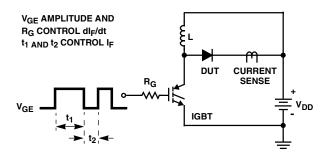


FIGURE 5. t<sub>rr</sub> TEST CIRCUIT

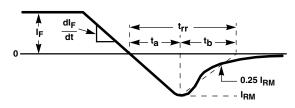


FIGURE 6. t<sub>rr</sub> WAVEFORMS AND DEFINITIONS

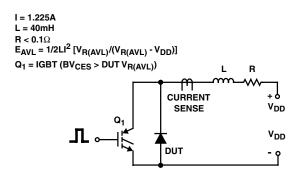


FIGURE 7. AVALANCHE ENERGY TEST CIRCUIT

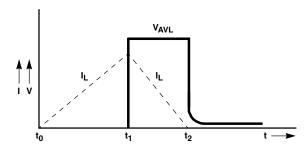


FIGURE 8. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

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DOME™	ISOPLANAR™	QT Optoelectronics™	UHC <sup>TM</sup>
EcoSPARK™	LittleFET™	Quiet Series™	UltraFET™
E <sup>2</sup> CMOS <sup>TM</sup>	MicroFET™	SILENT SWITCHER ®	$VCX^{TM}$
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Datasheet Identification	Product Status	Definition
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